

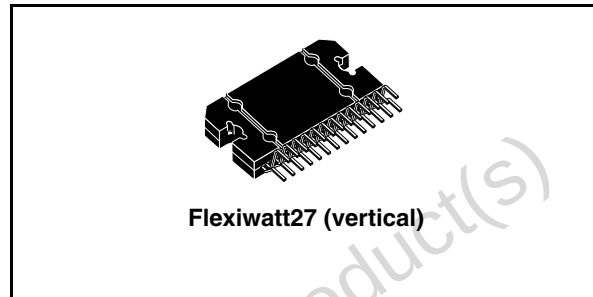
4 x 45 W quad bridge car radio amplifier

Feature

- Superior output power capability:
 - 4 x 50 W/4 Ω max.
 - 4 x 45 W/4 Ω EIAJ
 - 4 x 30 W/4 Ω @ 14.4 V, 1 kHz, 10 %
 - 4 x 80 W/2 Ω max.
 - 4 x 77 W/2 Ω EIAJ
 - 4 x 55 W/2 Ω @ 14.4 V, 1 kHz, 10 %
- Multipower BCD technology
- MOSFET output power stage
- Excellent 2 Ω driving capability
- Hi-fi class distortion
- Low output noise
- Standby function
- Mute function
- Automute at min. supply voltage detection
- Low external component count:
 - Internally fixed gain (26 dB)
 - No external compensation
 - No bootstrap capacitors
- On board 0.35 A high side driver

Protections

- Output short circuit to GND, to V_S , across the load
- Very inductive loads



- Overrating chip temperature with soft thermal limiter
- Output DC offset detection
- Load dump voltage
- Fortuitous open GND
- Reversed battery
- ESD

Description

The TDA7560A is a breakthrough BCD (Bipolar / CMOS / DMOS) technology class AB audio power amplifier in Flexiwatt 27 package designed for high power car radio.

The fully complementary P-Channel/N-Channel output structure allows a rail to rail output voltage swing which, combined with high output current and minimized saturation losses sets new power references in the car-radio field, with unparalleled distortion performances.

Table 1. Device summary

Order code	Package	Packing
E-TDA7560A	Flexiwatt27 (vertical)	Tube

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Obsolete Product(s) - Obsolete Product(s)

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1 Block and pin connection diagrams

Figure 1. Block diagram

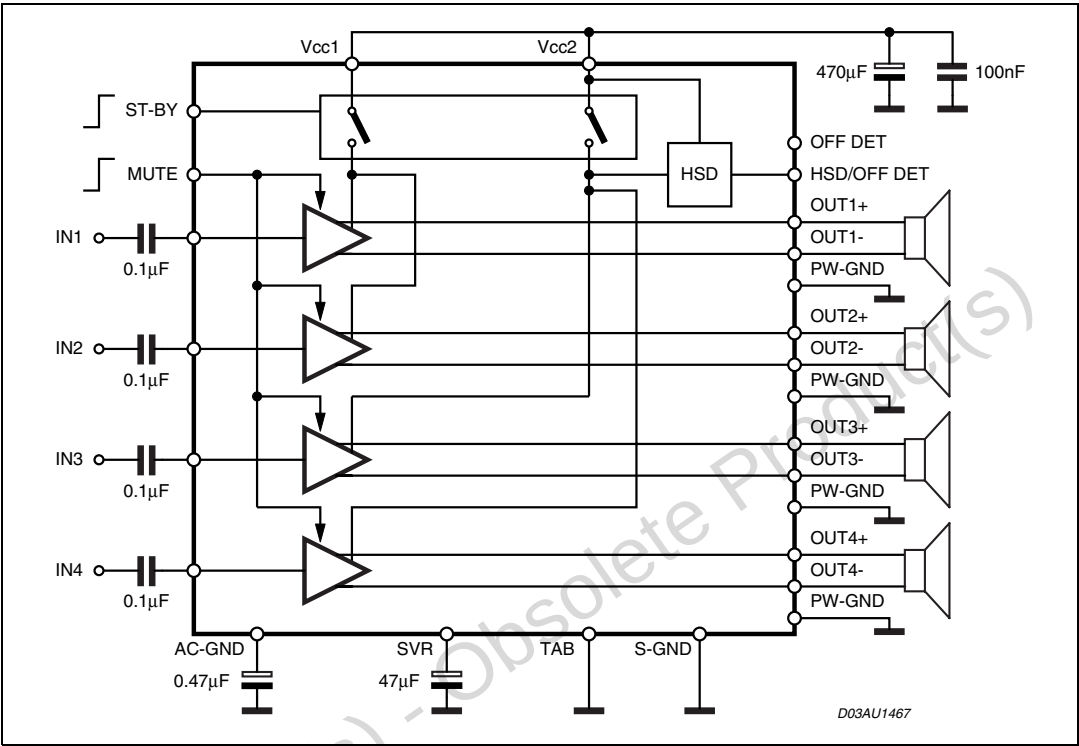
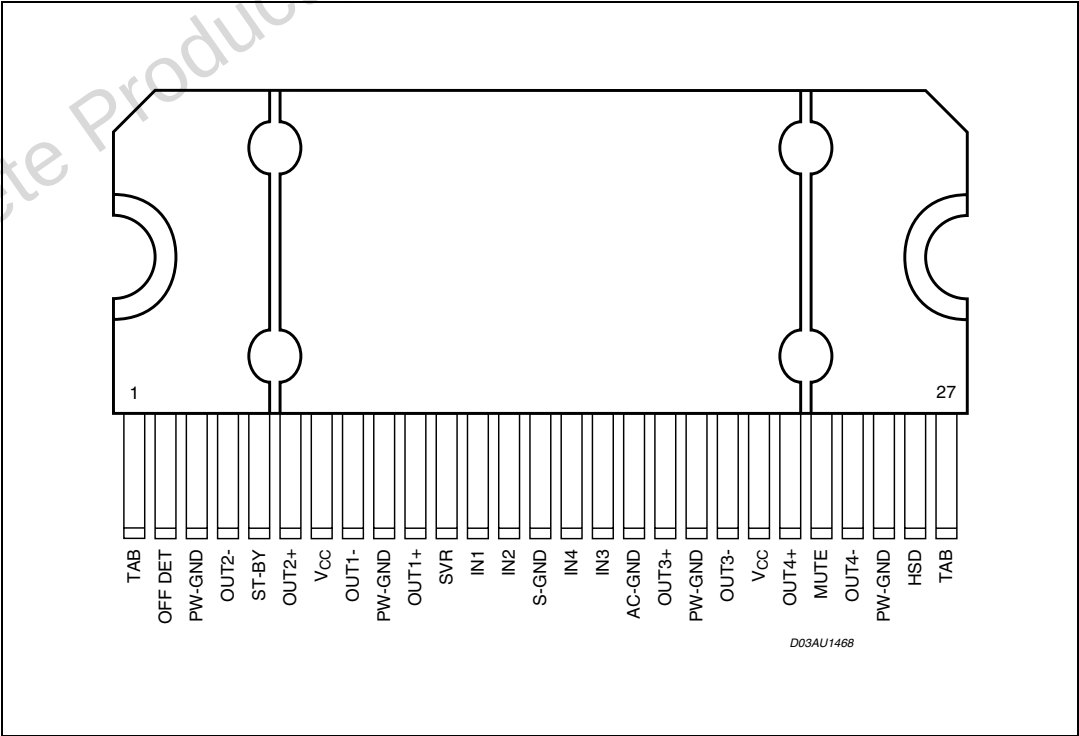


Figure 2. Pin connection (top view)



2 Electrical specifications

2.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Operating supply voltage	18	V
$V_{CC(DC)}$	DC supply voltage	28	V
$V_{CC(pk)}$	Peak supply voltage (for $t = 50$ ms)	50	V
I_O	Output peak current	9	A
	Repetitive (duty cycle 10 % at $f = 10$ Hz) Non repetitive ($t = 100$ μ s)	10	A
P_{tot}	Power dissipation $T_{case} = 70$ °C	85	W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-55 to 150	°C

2.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{th\ j-case}$	Thermal resistance junction to case	Max. 1	°C/W

2.3 Electrical characteristics

Table 4. Electrical characteristics

(Refer to the test and application diagram, $V_S = 13.2$ V; $R_L = 4$ Ω ; $R_g = 600$ Ω ; $f = 1$ kHz; $T_{amb} = 25$ °C; unless otherwise specified).

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
I_{q1}	Quiescent current	$R_L = \infty$	80	200	320	mA
V_{OS}	Output offset voltage	Play Mode			± 50	mV
dV_{OS}	During mute ON/OFF output offset voltage				± 60	mV
G_v	Voltage gain		25	26	27	dB
dG_v	Channel gain unbalance				± 1	dB
P_o	Output power	$V_S = 13.2$ V; THD = 10 %	23	25		W
		$V_S = 13.2$ V; THD = 1 %	16	19		
		$V_S = 14.4$ V; THD = 10 %	28	30		
		$V_S = 14.4$ V; THD = 1 %	20	23		

Table 4. Electrical characteristics (continued)

(Refer to the test and application diagram, $V_S = 13.2\text{ V}$; $R_L = 4\ \Omega$; $R_g = 600\ \Omega$; $f = 1\text{ kHz}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$; unless otherwise specified).

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
P_o	Output power	$V_S = 13.2\text{ V}$; THD = 10 %, $2\ \Omega$ $V_S = 13.2\text{ V}$; THD = 1 %, $2\ \Omega$ $V_S = 14.4\text{ V}$; THD = 10 %, $2\ \Omega$ $V_S = 14.4\text{ V}$; THD = 1 %, $2\ \Omega$	42 32 50 40	45 34 55 43		W
$P_{o\text{ EIAJ}}$	EIAJ output power ⁽¹⁾	$V_S = 13.7\text{ V}$; $R_L = 4\ \Omega$ $V_S = 13.7\text{ V}$; $R_L = 2\ \Omega$	41	45 77		W
$P_{o\text{ max.}}$	Max. output power ⁽¹⁾	$V_S = 14.4\text{ V}$; $R_L = 4\ \Omega$ $V_S = 14.4\text{ V}$; $R_L = 2\ \Omega$	43 75	50 80		W
THD	Distortion	$P_o = 4\text{ W}$ $P_o = 15\text{ W}$; $R_L = 2\ \Omega$		0.006 0.015	0.02 0.03	%
e_{No}	Output noise	"A" Weighted $Bw = 20\text{ Hz to }20\text{ kHz}$		35 50	50 70	μV
SVR	Supply voltage rejection	$f = 100\text{ Hz}$; $V_r = 1\text{ V}_{\text{rms}}$	50	70		dB
f_{ch}	High cut-off frequency	$P_o = 0.5\text{ W}$	100	300		kHz
R_i	Input impedance		80	100	120	$\text{K}\Omega$
C_T	Cross talk	$f = 1\text{ kHz}$ $P_o = 4\text{ W}$ $f = 10\text{ kHz}$ $P_o = 4\text{ W}$	60 50	70 60	- -	dB
I_{SB}	Standby current consumption	$V_{\text{ST-BY}} = 1.5\text{ V}$ $V_{\text{ST-BY}} = 0\text{ V}$			20 10	μA
I_{pin5}	ST-BY pin current	$V_{\text{ST-BY}} = 1.5\text{ V to }3.5\text{ V}$			± 10	μA
$V_{\text{SB out}}$	Standby out threshold voltage	(Amp: ON)	3.5			V
$V_{\text{SB in}}$	Standby in threshold voltage	(Amp: OFF)			1.5	V
A_M	Mute attenuation	$P_{\text{Oref}} = 4\text{ W}$	80	90		dB
$V_{\text{M out}}$	Mute out threshold voltage	(Amp: Play)	3.5			V
$V_{\text{M in}}$	Mute in threshold voltage	(Amp: Mute)			1.5	V
$V_{\text{AM in}}$	VS automute threshold	(Amp: Mute) $\text{Att} \geq 80\text{ dB}$; $P_{\text{Oref}} = 4\text{ W}$ (Amp: Play) $\text{Att} < 0.1\text{ dB}$; $P_o = 0.5\text{ W}$	6.5	7 7.5	 8	V
I_{pin23}	Muting pin current	$V_{\text{MUTE}} = 1.5\text{ V}$ (Sourced current) $V_{\text{MUTE}} = 3.5\text{ V}$	7 -5	12	18 18	μA μA
HSD section						
$V_{\text{M MAX}}$	Mute voltage for HSD operation				6	V
V_{dropout}	Dropout voltage	$I_o = 0.35\text{ A}$; $V_S = 9\text{ to }16\text{ V}$		0.25	0.6	V
I_{prot}	Current limits		400		800	mA

Table 4. Electrical characteristics (continued)

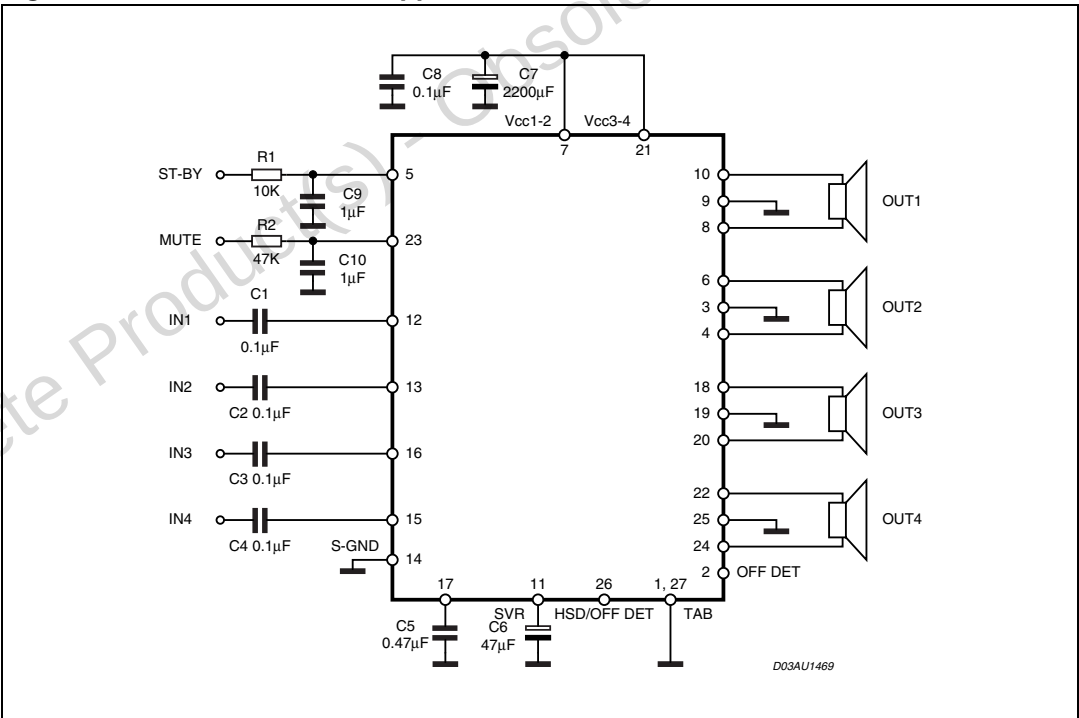
(Refer to the test and application diagram, $V_S = 13.2\text{ V}$; $R_L = 4\ \Omega$; $R_g = 600\ \Omega$; $f = 1\text{ kHz}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$; unless otherwise specified).

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
Offset detector (Pin 26)						
V_{M_ON}	Mute voltage for DC offset detection enabled	$V_{ST-BY} = 5\text{ V}$	8			V
V_{M_OFF}					6	V
V_{OFF}	Detected differential output offset	$V_{ST-BY} = 5\text{ V}$; $V_{\text{mute}} = 8\text{ V}$	± 2	± 3	± 4	V
V_{26_T}	Pin 26 voltage for detection = True	$V_{ST-BY} = 5\text{ V}$; $V_{\text{mute}} = 8\text{ V}$ $V_{OFF} > \pm 4\text{ V}$	0		1.5	V
V_{26_F}	Pin 26 voltage for detection = False	$V_{ST-BY} = 5\text{ V}$; $V_{\text{mute}} = 8\text{ V}$ $V_{OFF} > \pm 2\text{ V}$	12			V

1. Saturated square wave output.

2.4 Standard test and application circuit

Figure 3. Standard test and application circuit



2.5 Electrical characteristics curves

Figure 4. Quiescent current vs. supply voltage

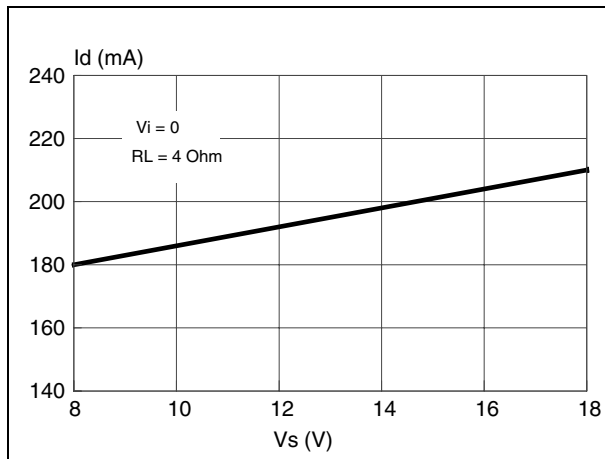


Figure 5. Output power vs. supply voltage ($R_L = 4\Omega$)

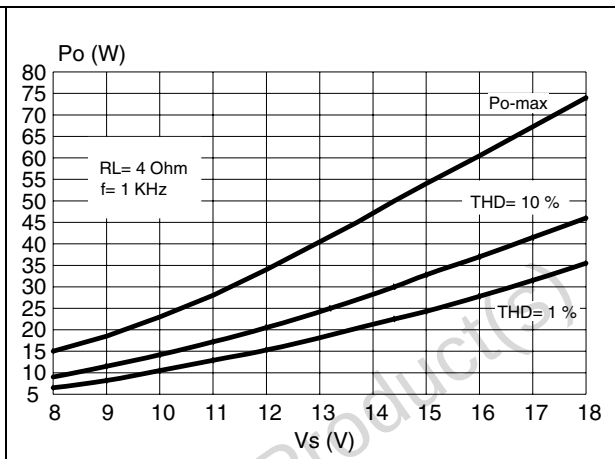


Figure 6. Output power vs. supply voltage ($R_L = 2\Omega$)

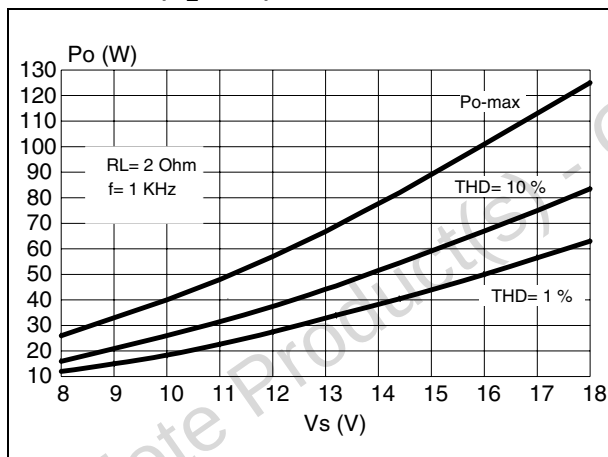


Figure 7. Distortion vs. output power ($R_L = 4\Omega$)

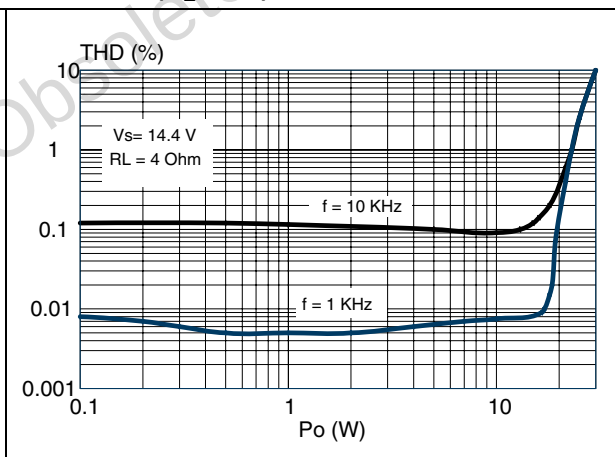


Figure 8. Distortion vs. output power ($R_L = 2\Omega$)

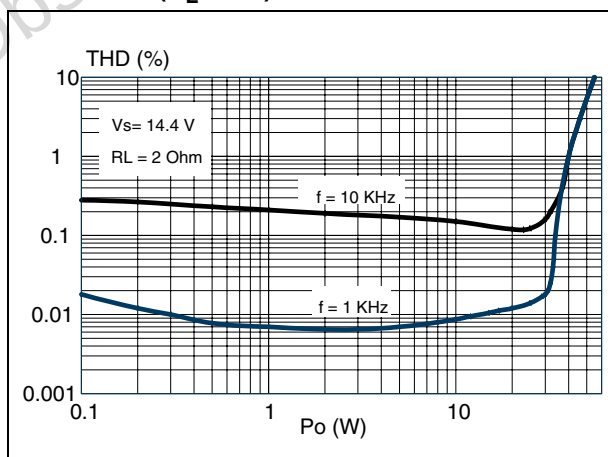


Figure 9. Distortion vs. frequency ($R_L = 4\Omega$)

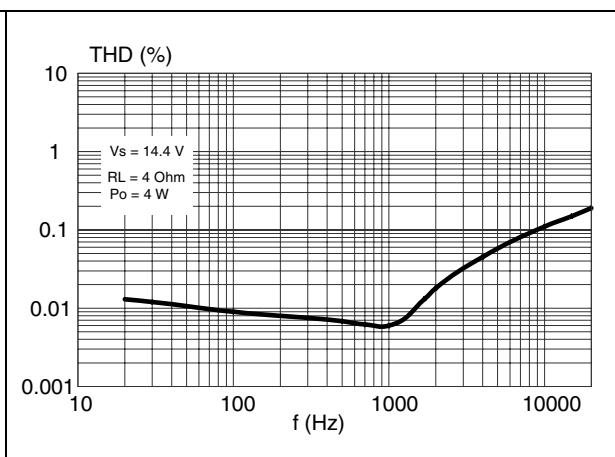


Figure 10. Distortion vs. frequency ($R_L = 2\Omega$)

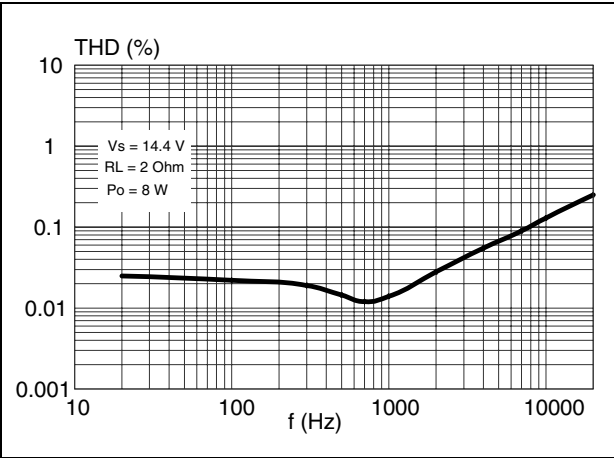


Figure 11. Crosstalk vs. frequency

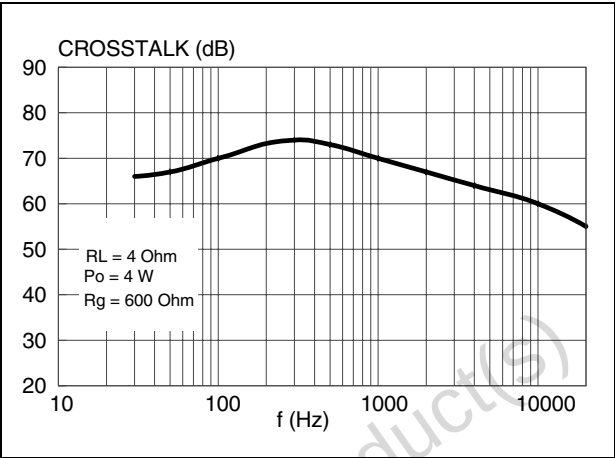


Figure 12. Supply voltage rejection vs. frequency

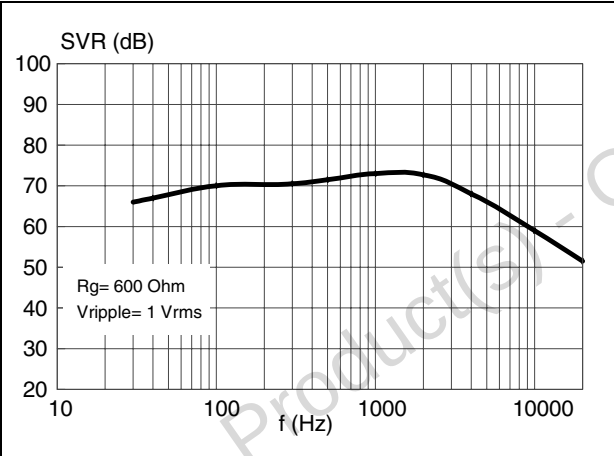


Figure 13. Output attenuation vs. supply voltage

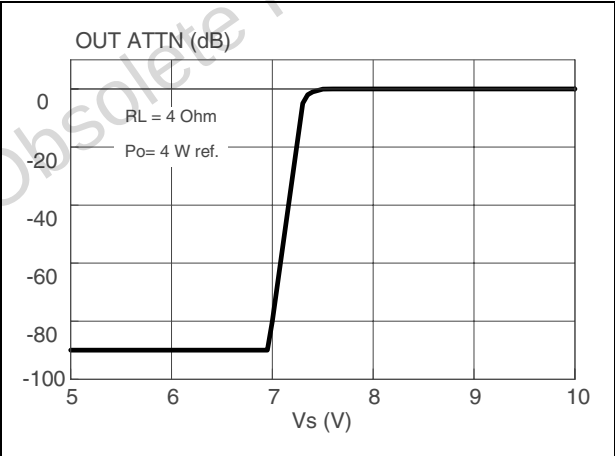


Figure 14. Output noise vs. source resistance

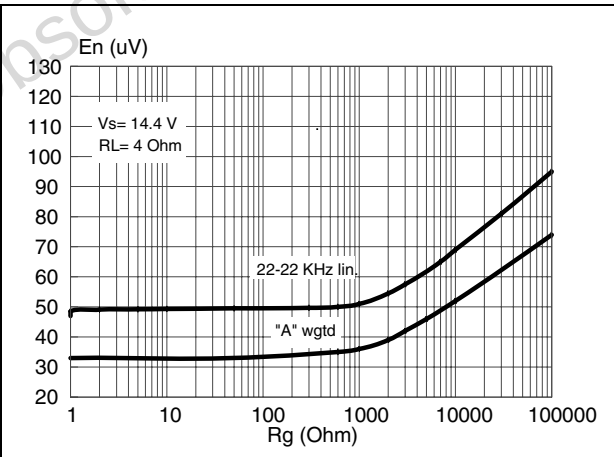


Figure 15. Power dissipation and efficiency vs. output power (sine-wave operation)

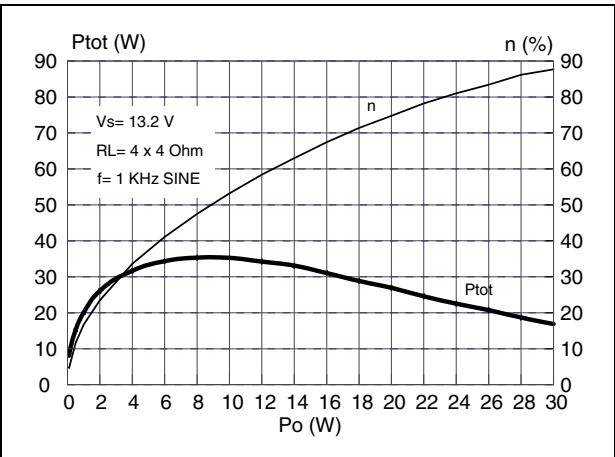


Figure 16. Power dissipation vs. output power (music/speech simulation);
 $R_L = 4 \times 4\Omega$

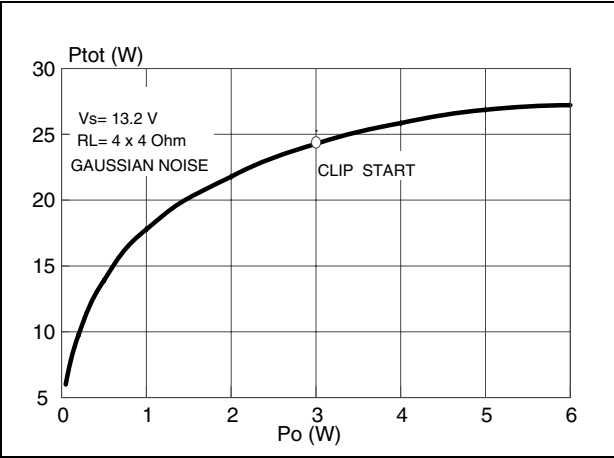


Figure 17. Power dissipation vs. output power (music/speech simulation);
 $R_L = 4 \times 2\Omega$

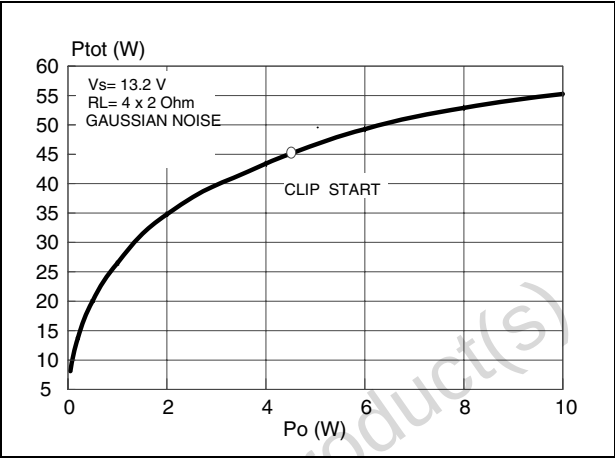
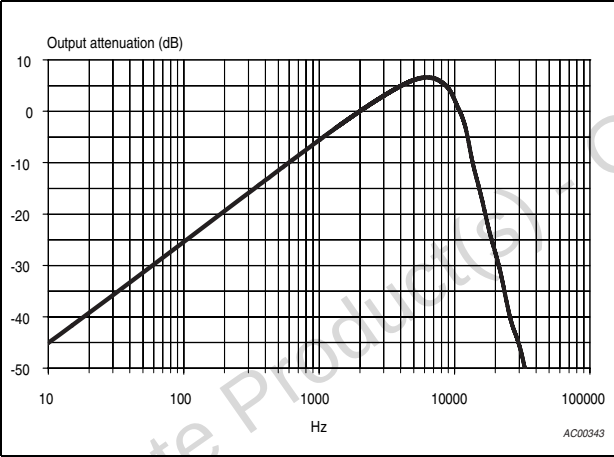


Figure 18. ITU R-ARM frequency response, weighting filter for transient pop



3 Application hints

(ref. to the circuit of [Figure 3](#))

3.1 SVR

Besides its contribution to the ripple rejection, the SVR capacitor governs the turn ON/OFF time sequence and, consequently, plays an essential role in the pop optimization during ON/OFF transients. To conveniently serve both needs, **ITS MINIMUM RECOMMENDED VALUE IS 10 μ F**.

3.2 Input stage

The TDA7560A's inputs are ground-compatible and can stand very high input signals (± 8 Vpk) without any performances degradation.

If the standard value for the input capacitors (0.1 μ F) is adopted, the low frequency cut-off will amount to 16 Hz.

3.3 Standby and muting

Standby and Muting facilities are both CMOS-compatible. In absence of true CMOS ports or microprocessors, a direct connection to Vs of these two pins is admissible but a 470 kOhm equivalent resistance should be present between the power supply and the muting and ST-BY pins.

R-C cells have always to be used in order to smooth down the transitions for preventing any audible transient noises.

About the standby, the time constant to be assigned in order to obtain a virtually pop-free transition has to be slower than 2.5 V/ms.

3.4 DC offset detector

The TDA7560A integrates a DC offset detector to avoid that an anomalous DC offset on the inputs of the amplifier may be multiplied by the gain and result in a dangerous large offset on the outputs which may lead to speakers damage for overheating. The feature is enabled by the MUTE pin (according to [Table 4](#)) and works with the amplifier unmuted and with no signal on the inputs.

The DC offset detection can be available at 2 different pins:

- Pin 2 (always enabled)
- Pin 26. Only enabled if Vmute (pin23) is set higher than 8V. If not ($V_{\text{mute}} < 6$ V) pin 26 will revert to the original HSD function

3.5 Heatsink definition

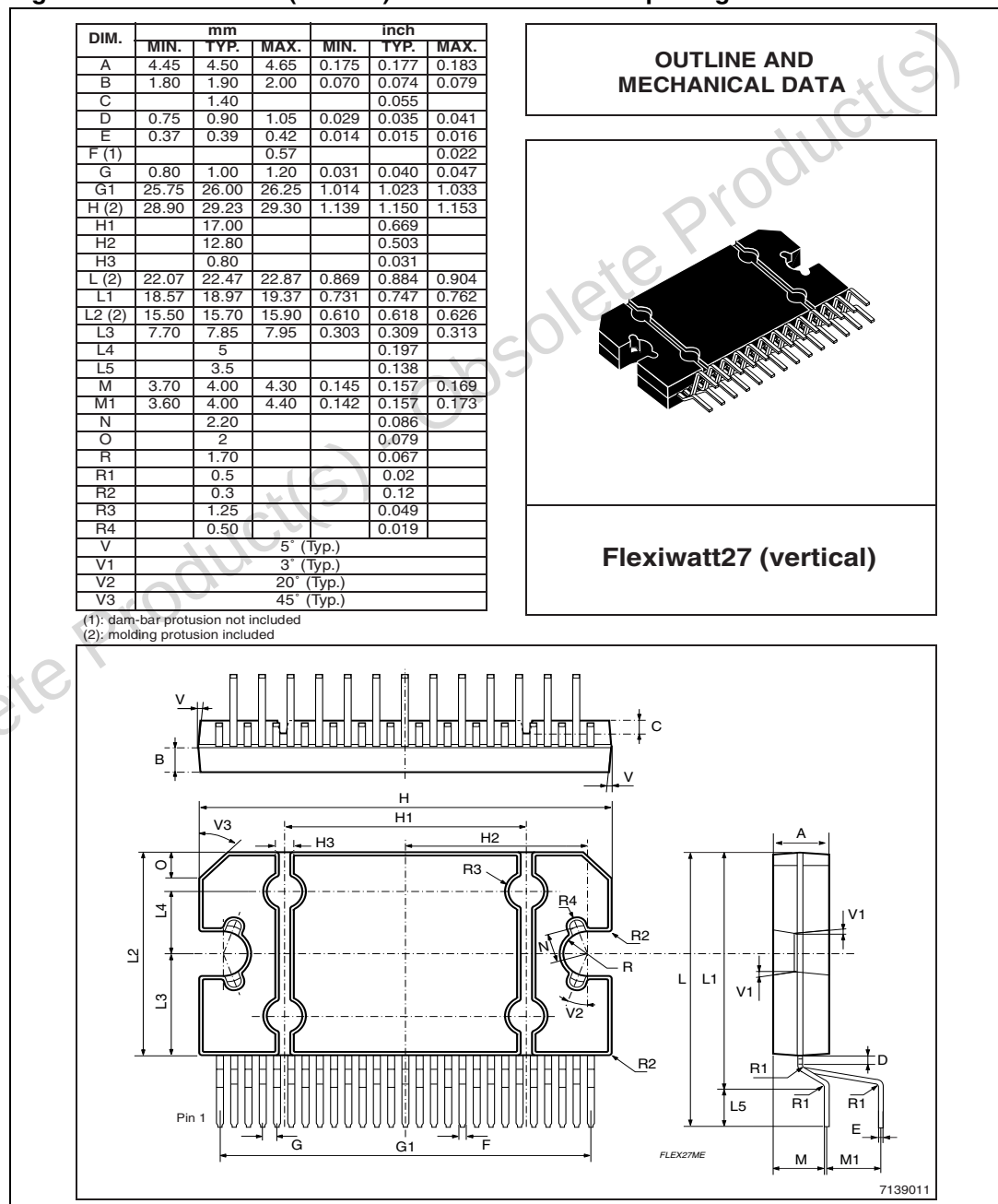
Under normal usage (4 Ohm speakers) the heatsink's thermal requirements have to be deduced from [Figure 16](#), which reports the simulated power dissipation when real music/speech programmes are played out. Noise with gaussian-distributed amplitude was employed for this simulation. Based on that, frequent clipping occurrence (worst-case) will cause $P_{\text{diss}} = 26$ W. Assuming $T_{\text{amb}} = 70$ °C and $T_{\text{CHIP}} = 150$ °C as boundary conditions, the heatsink's thermal resistance should be approximately 2 °C/W. This would avoid any thermal shutdown occurrence even after long-term and full-volume operation

4 Package information

In order to meet environmental requirements, ST (also) offers these devices in ECOPACK[®] packages. ECOPACK[®] packages are lead-free. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label.

ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Figure 19. Flexiwatt27 (vertical) mechanical data and package dimensions



5 Revision history

Table 5. Document revision history

Date	Revision	Changes
16-Mar-2003	1	Initial release.
29-Sep-2008	2	Document reformatted. Changed the order code, see Table 1: Device summary . Updated Table 4: Electrical characteristics . Added Figure 18: ITU R-ARM frequency response, weighting filter for transient pop .
07-Nov-2008	3	Modified max. values of the V_{OS} and THD parameter in Table 4: Electrical characteristics .

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